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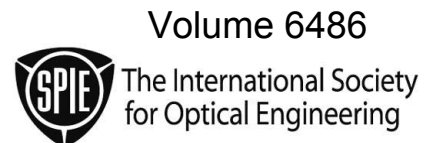
Light-Emitting Diodes: Research, Manufacturing, and Applications XI

Klaus P. Streubel
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